

SWITCHING

N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK3794 is N-channel MOS Field Effect Transistor designed for high current switching applications.

FEATURES

- Low On-state resistance
 $R_{DS(on)1} = 44 \text{ m}\Omega \text{ MAX. (} V_{GS} = 10 \text{ V, } I_D = 10 \text{ A)}$
 $R_{DS(on)2} = 78 \text{ m}\Omega \text{ MAX. (} V_{GS} = 4.0 \text{ V, } I_D = 10 \text{ A)}$
- Low C_{iss} : $C_{iss} = 760 \text{ pF TYP.}$
- Built-in gate protection diode
- TO-251/TO-252 package

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

Drain to Source Voltage ($V_{GS} = 0 \text{ V}$)	V_{DSS}	60	V
Gate to Source Voltage ($V_{DS} = 0 \text{ V}$)	V_{GSS}	± 20	V
Drain Current (DC) ($T_C = 25^\circ\text{C}$)	$I_{D(DC)}$	± 20	A
Drain Current (pulse) ^{Note1}	$I_{D(pulse)}$	± 50	A
Total Power Dissipation ($T_C = 25^\circ\text{C}$)	P_{T1}	30	W
Total Power Dissipation ($T_A = 25^\circ\text{C}$)	P_{T2}	1.0	W
Channel Temperature	T_{ch}	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to +150	$^\circ\text{C}$
Single Avalanche Current ^{Note2}	I_{AS}	15	A
Single Avalanche Energy ^{Note2}	E_{AS}	23	mJ
Repetitive Avalanche Energy ^{Note3}	E_{AR}	23	mJ

Notes 1. $PW \leq 10 \mu\text{s}$, Duty Cycle $\leq 1\%$

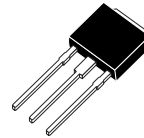
2. Starting $T_{ch} = 25^\circ\text{C}$, $V_{DD} = 30 \text{ V}$, $R_G = 25 \Omega$, $V_{GS} = 20 \rightarrow 0 \text{ V}$

3. $I_{AR} \leq 15 \text{ A}$, $T_{ch} \leq 150^\circ\text{C}$

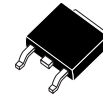
★ ORDERING INFORMATION

PART NUMBER	PACKAGE
2SK3794	TO-251 (MP-3)
2SK3794-Z	TO-252 (MP-3Z)

(TO-251)



(TO-252)



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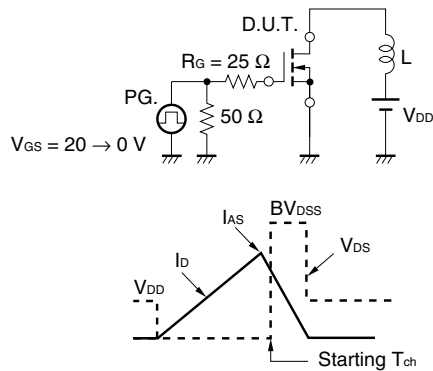
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ELECTRICAL CHARACTERISTICS (T_A = 25°C)

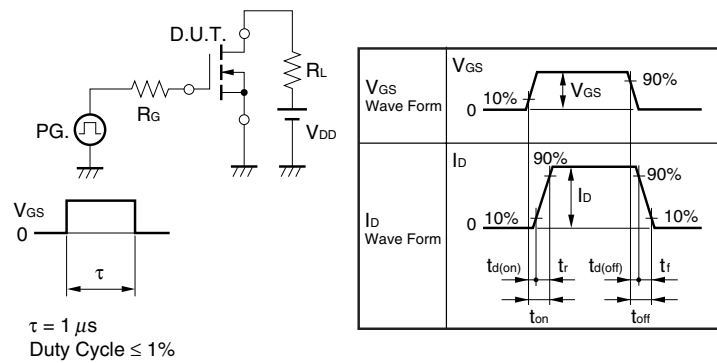
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 60 V, V _{GS} = 0 V			10	μA
Gate Leakage Current	I _{GSS}	V _{GS} = ±20 V, V _{DS} = 0 V			±10	μA
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.5	2.0	2.5	V
Forward Transfer Admittance Note	y _{fs}	V _{DS} = 10 V, I _D = 10 A	5	10		S
Drain to Source On-state Resistance Note	R _{DS(on)1}	V _{GS} = 10 V, I _D = 10 A		35	44	mΩ
	R _{DS(on)2}	V _{GS} = 4.0 V, I _D = 10 A		54	78	mΩ
Input Capacitance	C _{iss}	V _{DS} = 10 V		760		pF
Output Capacitance	C _{oss}	V _{GS} = 0 V		150		pF
Reverse Transfer Capacitance	C _{rss}	f = 1 MHz		71		pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = 30 V, I _D = 10 A		13		ns
Rise Time	t _r	V _{GS} = 10 V		170		ns
Turn-off Delay Time	t _{d(off)}	R _G = 10 Ω		43		ns
Fall Time	t _f			34		ns
Total Gate Charge	Q _G	V _{DD} = 48 V		17		nC
Gate to Source Charge	Q _{GS}	V _{GS} = 10 V		3.0		nC
Gate to Drain Charge	Q _{GD}	I _D = 10 A		4.7		nC
Body Diode Forward Voltage Note	V _{F(S-D)}	I _F = 20 A, V _{GS} = 0 V		1.0		V
Reverse Recovery Time	t _{rr}	I _F = 20 A, V _{GS} = 0 V		39		ns
Reverse Recovery Charge	Q _{rr}	di/dt = 100 A/μs		62		nC

Note Pulsed

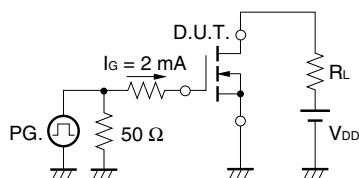
TEST CIRCUIT 1 AVALANCHE CAPABILITY



TEST CIRCUIT 2 SWITCHING TIME

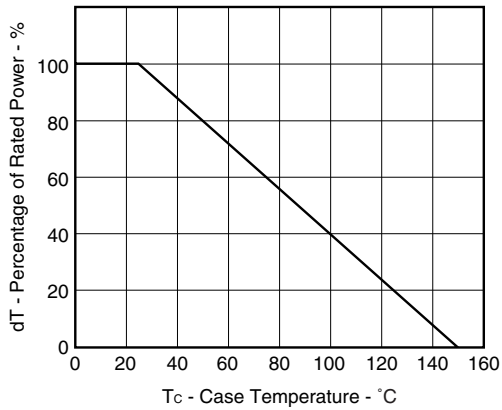


TEST CIRCUIT 3 GATE CHARGE

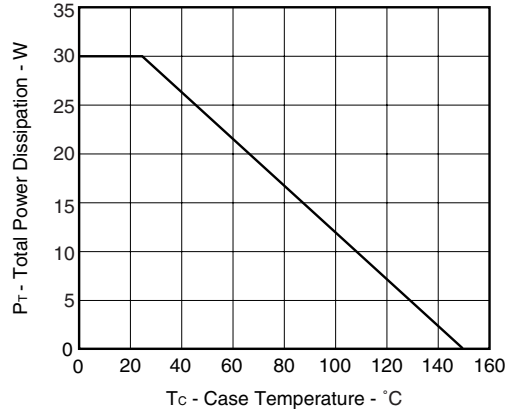


查询2SK3794 供应商 TYPICAL CHARACTERISTICS (T_A = 25°C)

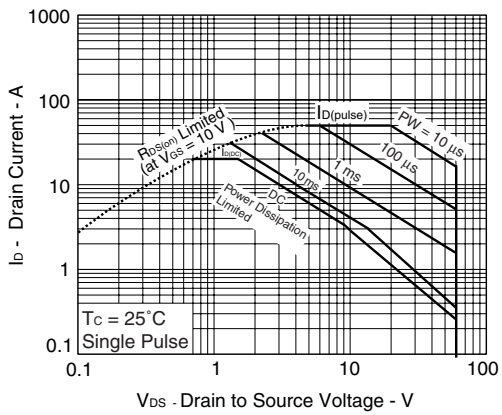
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



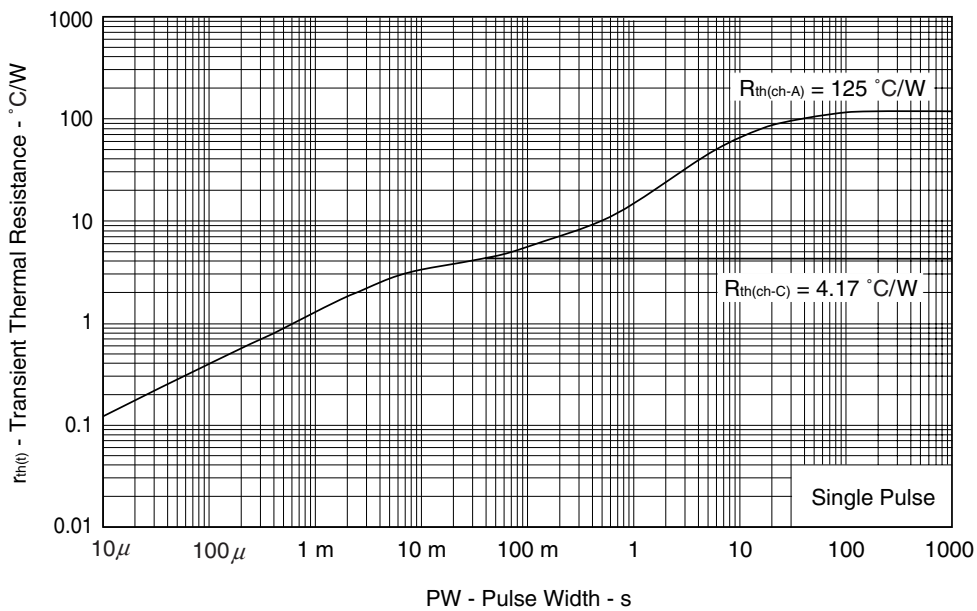
TOTAL POWER DISSIPATION vs. CASE TEMPERATURE



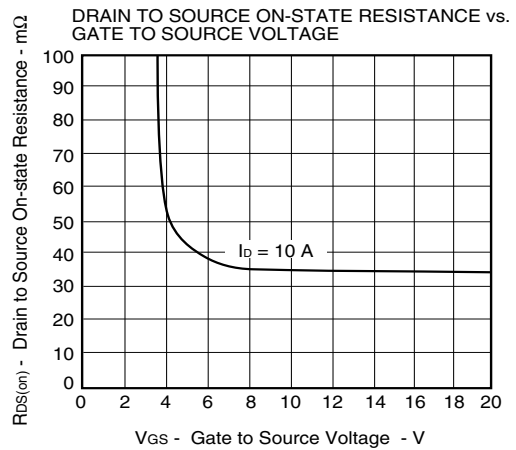
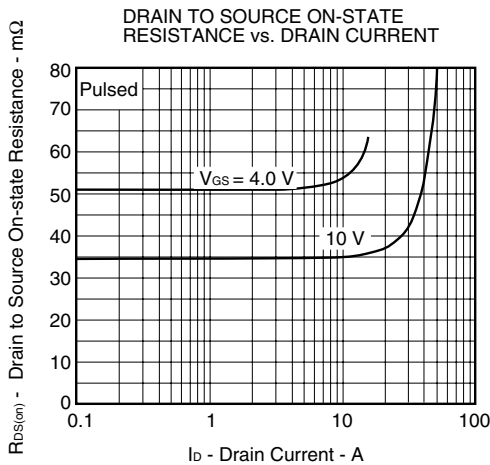
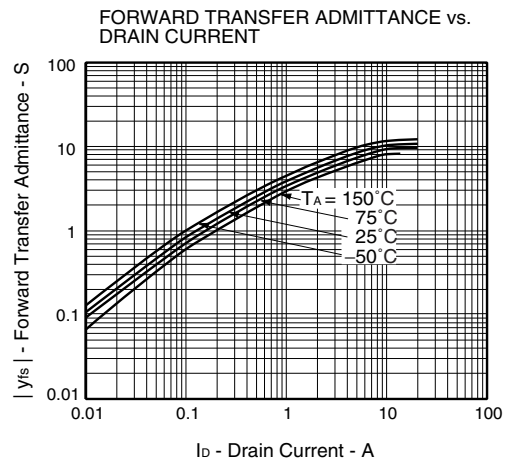
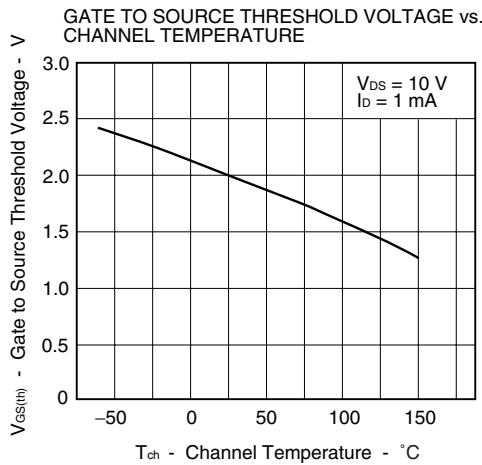
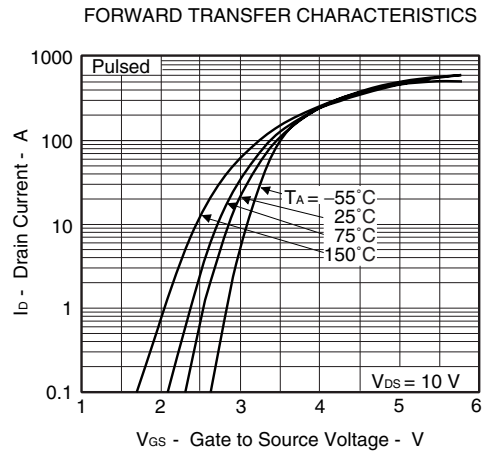
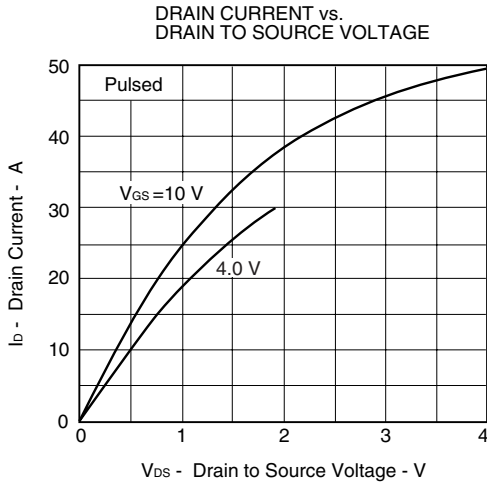
FORWARD BIAS SAFE OPERATING AREA



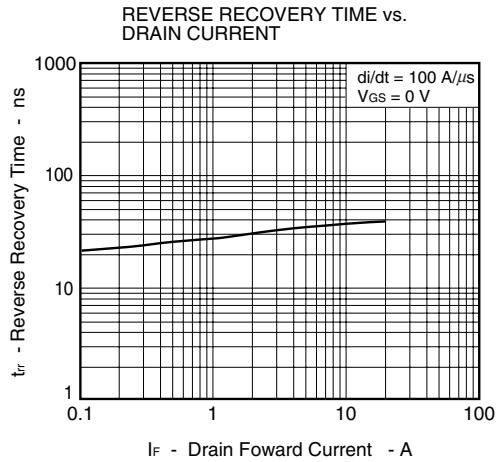
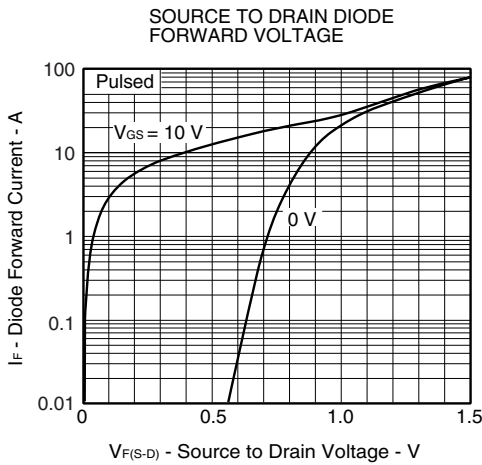
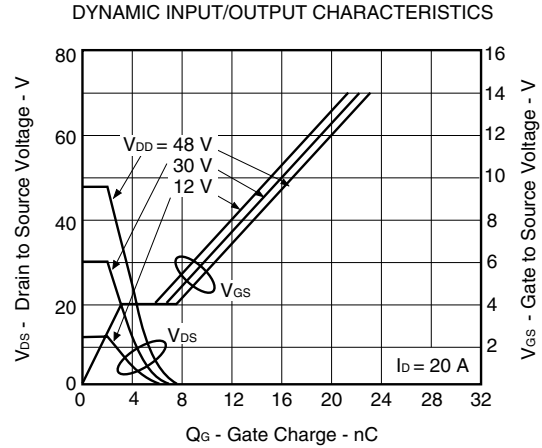
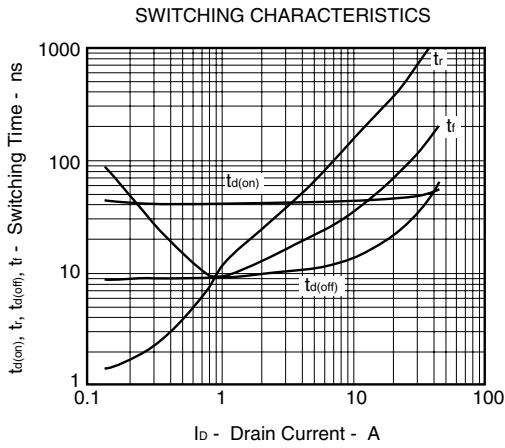
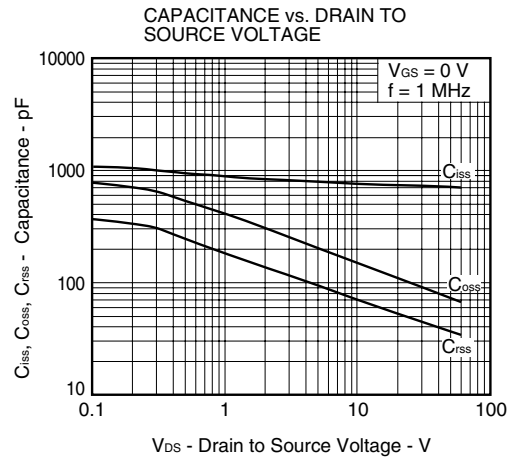
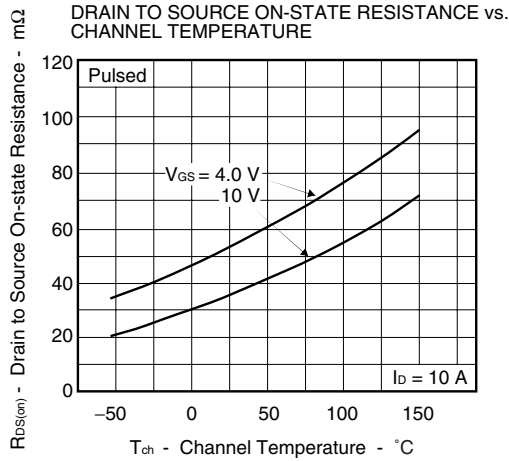
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



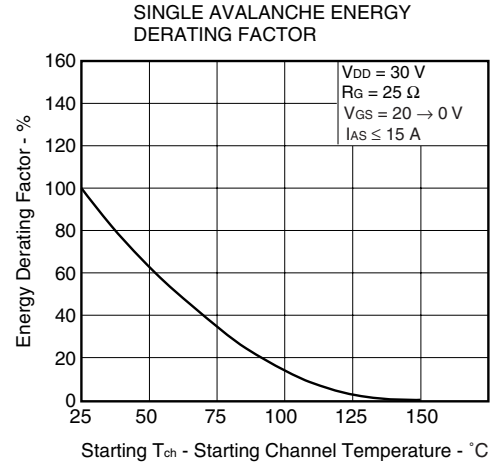
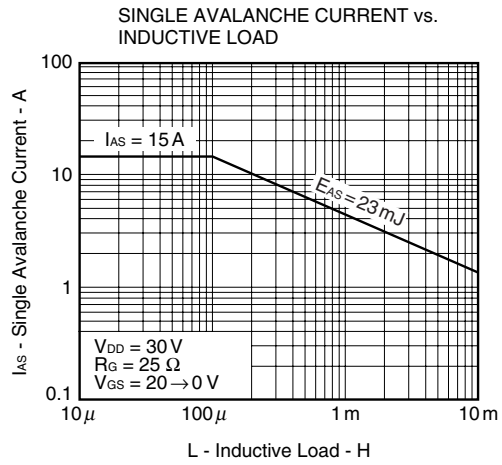
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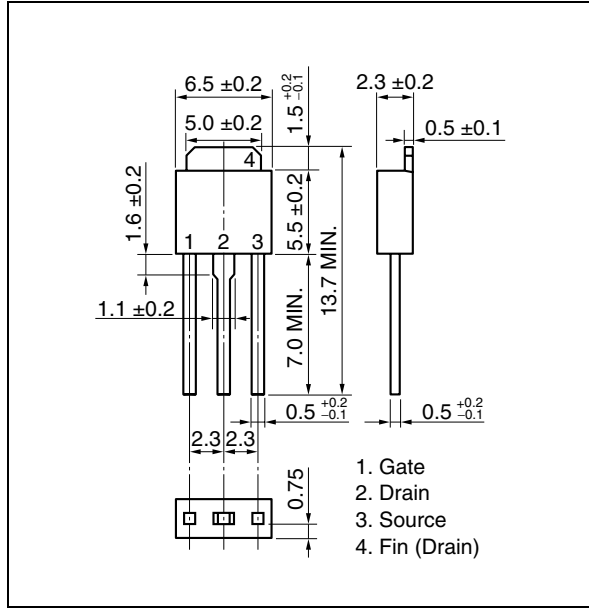


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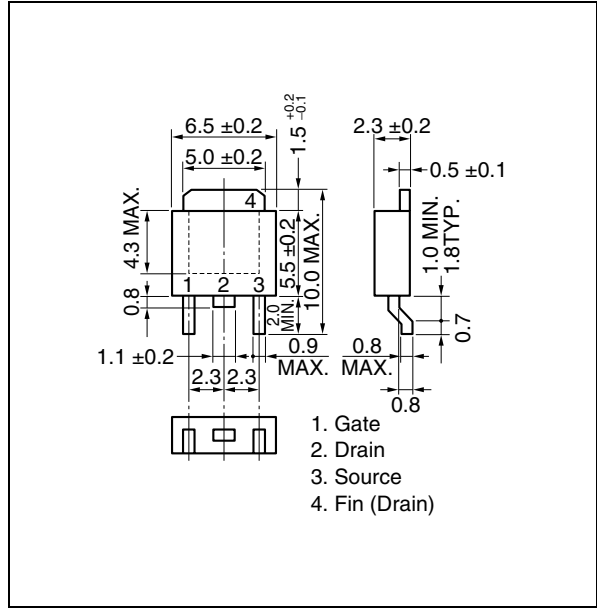


★[查询2SK3794 引脚图](#) PACKAGE DRAWINGS (Unit: mm)

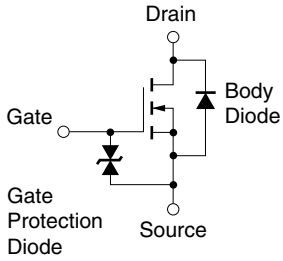
1) TO-251 (MP-3)



2) TO-252 (MP-3Z)



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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